

Si51211 Data Sheet

Three Output Factory Programmable Clock Generator

The factory programmable Si51211 is a low power, small footprint and frequency flexible programmable clock generator targeting low power, low cost and high volume consumer and embedded applications. The device operates from a single crystal or an external clock source and generates 1 to 3 outputs up to 170 MHz. The device is factory programmed to provide customized output frequencies and control input such as frequency select, spread spectrum on, power down and output enable. Center spread spectrum can also be programmed to reduce EMI to meet board level system requirements.

Applications

- · Crystal/XO replacement
- · EMI reduction
- · Portable devices

- Digital still camera
- IP phone
- Smart meter

KEY FEATURES

- Generates up to 3 CMOS clock outputs from 3 to 170 MHz
- Accepts crystal or reference clock input
 3 to 165 MHz reference clock input
 - 8 to 48 MHz crystal input
- Programmable FSEL, SSONb, PD, and OE input functions



1. Feature List

The Si51211 highlighted features are listed below.

- · Generates up to 3 CMOS clock outputs from 3 to 170 MHz
- Accepts crystal or reference clock input
 - 3 to 165 MHz reference clock input
 - 8 to 48 MHz crystal input
- Programmable FSEL, SSONb, PD, and OE input functions
- · Low power dissipation

- Separate voltage supply pins
 - + V_{DD} = 2.5 to 3.3 V
 - V_{DDO} = 1.8 to 3.3 V ($V_{DDO} \leq V_{DD}$)
- ±0.25%, ±0.5% or ±1% spread spectrum (center spread)
- · Low cycle-cycle jitter
- Ultra small 8-pin TDFN package (1.4 mm x 1.6 mm)

2. Design Considerations

2.1 Typical Application Schematic



2.2 Comments and Recommendations

Decoupling Capacitor: A decoupling capacitor of 0.1 μ F must be used between VDD and VSS on pins 1 and 8. Place the capacitor on the component side of the PCB as close to the VDD pin as possible. The PCB trace to the VDD pin and to the GND via should be kept as short as possible. Do not use vias between the decoupling capacitor and the VDD pin. In addition, a 10 μ F capacitor should be placed between VDD and VSS.

Series Termination Resistor: A series termination resistor is recommended if the distance between the outputs (SSCLK or REFCLK pins) and the load is over 1 $\frac{1}{2}$ inches. The nominal impedance of the SSCLK output is about 30 Ω . Use a 20 Ω resistor in series with the output to terminate a 50 Ω trace impedance and place a 20 Ω resistor as close to the SSCLK output as possible.

Crystal and Crystal Load: Only use a parallel resonant fundamental AT cut crystal. Do not use higher overtone crystals. To meet the crystal initial accuracy specification (in ppm) make sure that the external crystal load capacitor is matched to the crystal load specification. To determine the value of CL1 and CL2, use the following formula:

CL1 = CL2 = 2CL - (Cpin + Cp);

where CL is the load capacitance stated by the crystal manufacturer,

Cpin is the Si51211 pin capacitance (3 pF), and

Cp is the parasitic capacitance of the PCB traces.

Example: If a crystal with CL = 12 pF specification is used and Cp = 1 pF (parasitic PCB capacitance on PCB), 19 or 20 pF external capacitors from pins XIN (pin 2) and XOUT (Pin 3) to VSS are required. Users must verify Cp value.

Table 2.1. Crystal Specifications

Equivalent Series Resistance (ESR)	Crystal Output Capacitance (CO)	Load Capacitance (CL)
<u>≤</u> 50 Ω	≤ 3 pF	<u>≤</u> 13 pF

3. Electrical Specifications

Table 3.1. DC Electrical Specifications

(V_{DD} = 2.5 V ±10%, or V_{DD} = 3.3V ±-10%, V_{DDO} = V_{DD}, C_L = 10 pF, T_A = -40 to 85 °C)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Operating Voltage	V _{DD}	V _{DD} = 3.3 V ± 10%	2.97	3.3	3.63	V
		V _{DD} = 2.5 V ± 10%	2.25	2.5	2.75	V
	V _{DDO}	$V_{DDO} \leq V_{DD}$	1.71	_	3.6	V
Output High Voltage	V _{OH}	I _{OH} =4 mA, V _{DDX} = V _{DD} or V _{DDO}	V _{DDX} – 0.5	_	-	V
Output Low Voltage	V _{OL}	I _{OL} = 4 mA	_		0.3	V
Input High Voltage	VIH	CMOS Level	0.7 V _{DD}	_	_	V
Input Low Voltage	V _{IL}	CMOS Level	0		0.3 V _{DD}	V
Operating Supply Current ¹	I _{DD}	$\label{eq:FIN} \begin{array}{l} F_{IN} = 12 \; MHz, \; SSCLK1 = 12 \; MHz, \\ SSCLK2 = 24 \; MHz, \; C_L = 5 \; pF, \; V_{DD} \\ = \; V_{DDO} = 3.3 \; V \end{array}$	—	6.3	10	mA
Power Down Current		IDD _{PD}	_	0.5	0.65	mA
Nominal Output Impedance	Z _O		_	30	_	Ω
Internal Pull-up/Pull-down Resistor	R _{PUP} /R _{PD}	Pin 6	_	150k	_	Ω
Input Pin Capacitance	C _{IN}	Input pin capacitance		3	5	pF
Load Capacitance	CL		—	_	10	pF

 $1.\,I_{\text{DD}}$ depends on input and output frequency configurations.

Table 3.2. AC Electrical Specifications

 $(V_{DD} = 2.5 \text{ V} \pm 10\%, \text{ or } V_{DD} = 3.3 \text{ V} \pm 10\%, V_{DDO} = V_{DD}, C_L = 10 \text{ pF}, T_A = -40 \text{ to } 85 \text{ °C})$

Parameter	Symbol	Condition	Min	Тур	Мах	Unit
Input Frequency Range	F _{IN1}	Crystal input	8	_	48	MHz
Input Frequency Range	F _{IN2}	Reference clock Input	3	_	165	MHz
Output Frequency Range	F _{OUT}	SSCLK1/2/3	3	_	170	MHz
Frequency Accuracy	F _{ACC}	Configuration dependent	_	0	_	ppm
Output Duty Cycle	DC _{OUT}	Measured at V _{DDO} /2	45	50	55	%
		F _{OUT} ≤ 75 MHz				
		Measured at V _{DDO} /2	40	50	60	%
		F _{OUT} > 75 MHz				
Input Duty Cycle	DC _{IN}	CLKIN, CLKOUT through PLL	30	50	70	%

Parameter	Symbol	Condition	Min	Тур	Мах	Unit
Output Rise/Fall Time	t _r /t _f	C _L = 10 pF, 20 to 80%	—	1	2	ns
Period Jitter	PJ ₁	SSCLK1/2/3, at the same frequen- cy	_	12	20	ps rms
	PJ ₂	SSCLK1/2/3, at different output fre- quencies ¹	_	30	95 ²	ps rms
Cycle-to-Cycle Jitter	CCJ ₁	SSCLK1/2/3, at the same frequen- cy	_	85	150	ps
	CCJ ₂	SSCLK1/2/3, at different output fre- quencies ¹	_	145	290 ²	ps
Power-up Time	t _{PU}	Time from 0.9 V _{DD} to valid frequencies at all clock outputs		1.2	5	ms
Output Enable Time	t _{OE}	Time from OE rising edge to active at outputs SSCLK1/2 (asynchro- nous), F _{OUT} = 133 MHz	_	15	_	ns
Output Disable Time	t _{OD}	Time from OE falling edge to active at outputs SSCLK1/2 (asynchro- nous), F _{OUT} = 133 MHz	_	15	_	ns
Spread Spectrum Modulation Rate ³	SS _{DEV}		—	37	—	kHz

Note:

1. Example frequency configurations:

- 8 MHz, 100 MHz, 75 MHz
- 48 MHz, 100 MHz, 66 2/3 MHz
- 96 MHz, 133 1/3 MHz, 133 1/3 MHz

2. Jitter performance depends on configuration and programming parameters.

3. The SS modulation rate is a fixed ratio of the reference frequency with values in the range of 30 kHz to 50 kHz based on the frequency plan.

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Main Supply Voltage	V _{DD}		-0.5	_	4.2	V
Input Voltage	V _{IN}	Relative to V _{SS}	-0.5		V _{DD} +0.5	V
Temperature, Storage	Τ _S	Non-functional	-65	_	150	°C
Temperature, Operating Ambient	T _A	Functional, I-Grade	-40	—	85	°C
ESD Protection (Human Body Mod- el)	ESD _{HBM}	JEDEC (JESD 22-A114)	-4000		4000	V
ESD Protection (Charge Device Model)	ESD _{CDM}	JEDEC (JESD 22-C101)	-1500	_	1500	V
ESD Protection (Machine Model)	ESD _{MM}	JEDEC (JESD 22-A115)	-200		200	V

Table 3.3. Absolute Maximum Conditions

Note:

1. While using multiple power supplies, the Voltage on any input or I/O pin cannot exceed the power pin during power-up. Power supply sequencing is not required.

4. Functional Description

4.1 Input Frequency Range

The input frequency range is from 8.0 to 48.0 MHz for crystals and ceramic resonators. If an external clock is used, the input frequency range is from 3.0 to 165.0 MHz.

4.2 Output Frequency Range and Outputs

Up to three outputs can be programmed as SSCLK or REFCLK. SSCLK output can be synthesized to any value from 3 to 170 MHz with spread based on valid input frequency. The spread at the SSCLK pins can be enabled or disabled by the SSONb input control pin. If SSONb is used, when this pin is pulled high (V_{DD}), the frequency at SSCLK pin is synthesized to the nominal value of the input frequency without spread. If low (GND), the frequency at SSCLK is synthesized to the nominal value of the input frequency.

REFCLK is the buffered output of the oscillator and is the same frequency as the input frequency without spread. By using only low cost, fundamental mode crystals, the Si51211 can synthesize output frequency up to 170 MHz, eliminating the need for higher order crystals (Xtals) and crystal oscillators (XOs). This reduces the cost while improving the system clock accuracy, performance, and reliability.

4.3 Programmable Spread Percent (%)

The spread percent (%) value is programmable to ±0.25%, ±0.5% or ±1% (center spread) for all SSCLK frequencies.

4.4 SSONb or Frequency Select (FSEL)

The Si51211 pins 4 and 6 can be programmed as SSONb to enable or disable the programmed spread percent value. If SSONb is used, when this pin is pulled high (V_{DD}),the frequency at SSCLK pin is synthesized to the nominal value of the input frequency without spread. If low (GND), the frequency at SSCLK is synthesized to the nominal value of the input frequency with spread. Pin 4 can also be programmed as frequency select (FSEL) function.

If FSEL function is used, the output pin can be programmed for different set of frequencies as selected by FSEL. SSCLK value can be any frequency from 3 to up to 170 MHz, but the spread % is the same percent value. REFCLK is the same frequency as the input reference clock. The set of frequencies in the table below are given as an example, using a 48 MHz crystal.

Table 4.1.	Example	Frequencies
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FSEL	SSCLK1
Pin 4	Pin 6
0	66 MHz, ±1%
1	33 MHz, ±1%

4.5 Power Down (PD) or Output Enable (OE)

The Si51211 pin 6 can be programmed as PD input. Pin 4 and pin 6 can be programmed as OE input. PD turns off both PLL and output buffers whereas OE only disables the output buffers to Hi-Z. The OE function is asynchronous. Any requirement for synchronous operations (like glitchless output clock switching) needs to be handled externally.

5. Pin Description



Figure 5.1. 8-Pin TDFN

Table 5.1. Si51211 8-Pin Descriptions

Pin #	Name	Туре	Description
1	VDD	PWR	2.5 to 3.3 V power supply.
2	XOUT	0	Crystal output. Leave this pin unconnected (floating) if an external clock input is used.
3	XIN/CLKIN	I	External crystal and clock input.
4	SSCLK1/REFCLK/FSEL/SSONb/OE	I/O	Programmable SSCLK1 or REFCLK output or MultiFunction con- trol input. The frequency at this pin is synthesized by the internal PLL if programmed as SSCLK1 with or without spread. If pro- grammed as REFCLK, output clock is a buffered output of crystal or reference clock input. If programmed as a MultiFunction control input, it can be OE, FSEL, and SSONb.
5	VSS	GND	Ground.
6	SSCLK2/SSONb/PD/OE	I/O	Programmable SSCLK2 output or MultiFunction control input. The frequency at this pin is synthesized by the internal PLL if programmed as SSCLK2 with or without spread. SSCLK2 output can also be programmed as a buffered output of crystal or reference clock input divided by N, $2 \le N \le 8$. If programmed as a MultiFunction control input, it can be OE, PD, and SSONb. This pin cannot be programmed as FSEL control input.
7	SSCLK3	0	Programmable SSCLK3 output. The frequency at this pin is synthesized by internal PLL with or without spread. It is powered by V_{DDO} pin (pin 8).
8	VDDO	PWR	1.8 to 3.3 V output power supply to SSCLK3 (pin 7) $V_{DDO} \leq V_{DD}$.

6. Ordering Guide

Table 6.1. Si51211 Ordering Guide

Part Number	Package Type	Temperature
Si51211-Axxxxx-GM	8-pin TDFN	Industrial, –40 to 85 °C
Si51211-Axxxxx-GMR	8-pin TDFN—Tape and Reel	Industrial, –40 to 85 °C



7. Package Outline

A1 🛓



Figure 7.1. 8-pin TDFN

Table 7.1.	Si51211	Package	Dimensions
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Dimension	m	m	mils		
Symbol	Min	Мах	Min	Мах	
A	0.70	0.80	27.56	31.50	
A1	0	0.05	0	1.97	
A3	0.175	0.225	6.89	8.86	
D	1.3	1.5	51.18	59.06	
E	1.5	1.7	59.06	66.93	
D2	0.20	0.30	7.87	11.81	
E2	1.0	1.1	39.37	43.31	
е	0.4 BSC		15.75	BSC	
NX b	0.15	0.25	5.91	9.84	
NX L	0.25	0.45	9.84	17.72	
0 °	0 °	4 °	0 °	4 °	
ND		0			
NE		2	4		

Dimension	m	m	mils	
Symbol	Min	Мах	Min Max	

Note:

1. Spade width, lead width and lead thickness exclusive of solder plate.

- 2. Package outline exclusive of mold flashes and burr dimensions.
- 3. Coplanarity applies to the exposed pad as well as the terminals. Coplanarity shall not exceed 0.08 mm.
- 4. Warpage shall not exceed 0.10 mm.
- 5. The Terminal #1 identifier and terminal numbering convention shall conform to JESD 95-1 SPP-012. Details of Terminal #1 identifier are optional, but must be located within the zone indicated. The Terminal #1 identifier may be either a mold or marked feature.
- 6. ND and NE refer to the number of terminals on each D and E side respectively.

8. PCB Land Pattern

The figure below illustrates the PCB land pattern details for the device. The table below lists the values for the dimensions shown in the illustration.



Figure 8.1. Si51211 8-pin TDFN PCB Land Pattern

Table 8.1.	PCB Lan	d Pattern	Dimensions
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Dimension	mm
D	1.00
E	0.40
L	0.5
W	0.3
X1	1.05
Y1	0.25

Dimension	mm	
Note:		
General		
1. All dimensions shown are in millimeters (mm).		
2. This Land Pattern Design is based on the IPC-7351 guideline	es.	
 All dimensions shown are at Maximum Material Condition (M allowance of 0.05 mm. 	MC). Least Material Condition is calculated based on a fabrication	
Solder Mask Design		
 All metal pads are to be non-solder mask defined (NSMD). C minimum, all the way around the pad. 	learance between the solder mask and the metal pad is to be 60 μm	
Stencil Design		
1. A stainless steel, laser-cut and electro-polished stencil with tr	apezoidal walls should be used to assure good solder paste release.	
2. The stencil thickness should be 0.125 mm (5 mils).		
3. The ratio of stencil aperture to land pad size should be 1:1 for	r all perimeter pads.	
4. A 2x1 array of 0.55 mm square openings on 0.90 mm pitch sl	hould be used for the center ground pad.	
Card Assembly		

1. A No-Clean, Type-3 solder paste is recommended.

2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

9. Revision History

9.1 Revision 1.0

April 20, 2016

- Updated max output frequency to 170 MHz
- · Updated max clock input frequency to 165 MHz
- Updated Operating Temperature to Industrial temperature, –40 °C to 85 °C
- Updated PD programmable active state
- · Removed programmable output rise/fall time, SSEL.
- Updated Table 3.1 DC Electrical Specifications on page 3
- Updated Table 3.2 AC Electrical Specifications on page 3
- · Updated pin descriptions in Pin Descriptions
- · Updated customized part numbering nomenclature in 6. Ordering Guide
- · Added land pattern drawing

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